

MH189 Hall-effect sensor is a temperature stable, stress-resistant sensor. Superior high-temperature performance is made possible through a dynamic offset cancellation that utilizes chopper-stabilization. This method reduces the offset voltage normally caused by device over molding, temperature dependencies, and thermal stress.

MH189 includes the following on a single silicon chip: voltage regulator, Hall voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, Open drain output. Advanced CMOS wafer fabrication processing is used to take advantage of low-voltage requirements, component matching, very low input-offset errors, and small component geometries.

This device requires the presence of both south and north polarity magnetic fields for operation. In the presence of a south polarity field of sufficient strength, the device output sensor on, and only switches off when a north polarity field of sufficient strength is present.

MH189 is rated for operation between the ambient temperatures -40°C and 85°C for the E temperature range, and -40°C to 125°C for the K temperature range. The two package styles available provide magnetically optimized solutions for most applications. Package SO is an SOT-23, a miniature low-profile surface-mount package, while package UA is a three-lead ultra mini SIP for through-hole mounting.

Packages is Halogen Free standard and which have been verified by third party lab.


Features and Benefits

- DMOS Hall IC Technology
- AECQ qualified
- Reverse bias protection on power supply pin.
- Chopper stabilized amplifier stage
- Optimized for BLDC motor applications
- Reliable and low shifting on high Temp condition
- Good ESD Protection
- 100% tested at 125°C for K.
- Custom sensitivity / Temperature selection are available.
- RoHS compliant 2011/65/EU and Halogen Free

Applications

- High temperature Fan motor
- 3 phase BLDC motor application
- Speed sensing
- Position sensing
- Current sensing
- Revolution counting
- Solid-State Switch
- Linear Position Detection
- Angular Position Detection
- Proximity Detection
- High ESD Capability

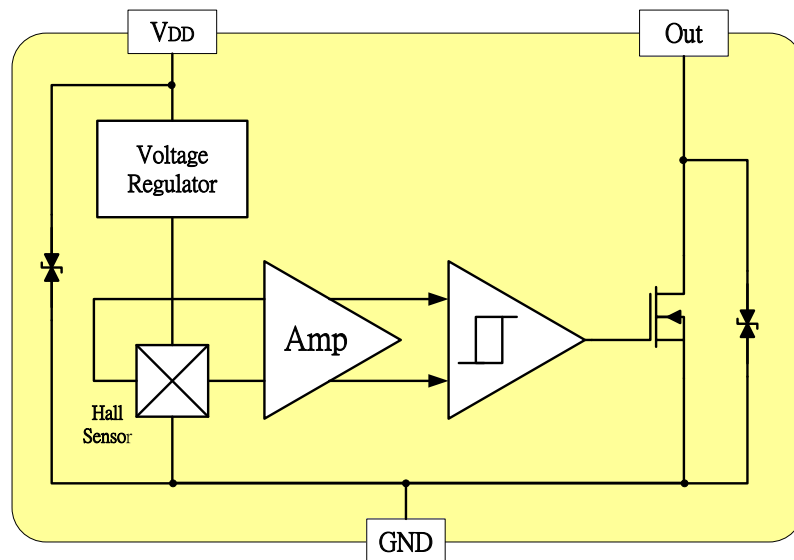
Ordering Information

	<p>Company Name and Product Category</p> <p>MH:MST Hall Effect/MP:MST Power MOSFET</p> <p>Part number</p> <p>181,182,183,184,185,248,249,276,477,381,381F,381R,382.....</p> <p>If part # is just 3 digits, the fourth digit will be omitted.</p> <p>Temperature range</p> <p>E: 85 °C, I: 105 °C, K: 125 °C, L: 150 °C</p> <p>Package type</p> <p>UA:TO-92S,VK:TO-92S(4pin),VF:TO-92S(5pin),SO:SOT-23, SQ:QFN-3,ST:TSOT-23,SN:SOT-553,SF:SOT-89(5pin),SH:D FN2*2-6L, SR:SOT-26L</p> <p>Sorting</p> <p>α,β,Blank.....</p>
<p>Sorting Code</p> <p>Package type</p> <p>Temperature Code</p> <p>Part number</p> <p>Company Name and product Category</p>	

Part No.	Temperature Suffix	Package Type
MH189KUA	K (-40°C to + 125°C)	UA (TO-92S)
MH189KSO	K (-40°C to + 125°C)	SO (SOT-23)
MH189EUA	E (-40°C to + 85°C)	UA (TO-92S)
MH189ESO	E (-40°C to + 85°C)	SO (SOT-23)

KUA spec is using in industrial and automotive application. Special Hot Testing is utilized.

Functional Diagram



Absolute Maximum Ratings At ($T_a=25\text{ }^\circ\text{C}$)

Characteristics	Values	Unit
Supply voltage, (V_{DD})	28	V
Output Voltage, (V_{out})	28	V
Reverse voltage, (V_{DD}) (V_{OUT})	-0.3	V
Output current, (I_{SINK})	50	mA
Operating Temperature Range, (T_a)	“E” version	-40 to +85 $^\circ\text{C}$
	“K” version	-40 to +125 $^\circ\text{C}$
Storage temperature range, (T_s)	-65 to +150	$^\circ\text{C}$
Maximum Junction Temp, (T_j)	150	$^\circ\text{C}$
Thermal Resistance	(θ_{ja}) UA / SO	206 / 543 $^\circ\text{C/W}$
	(θ_{jc}) UA / SO	148 / 410 $^\circ\text{C/W}$
Package Power Dissipation, (P_D) UA / SO	606 / 230	mW

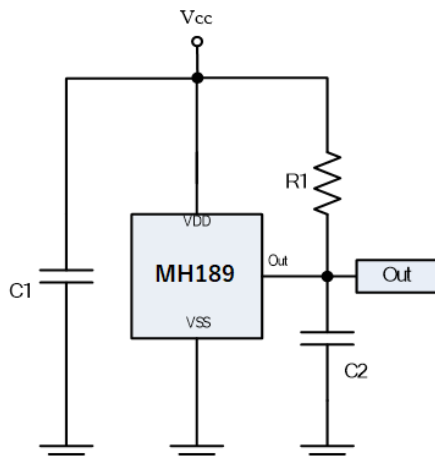
Note: Do not apply reverse voltage to V_{DD} and V_{OUT} Pin, It may be caused for Miss function or damaged device.

Electrical Specifications

DC Operating Parameters : $T_A=+25^\circ\text{C}$, $V_{DD}=12\text{V}$

Parameters	Test Conditions	Min	Typ	Max	Units
Supply Voltage, (V_{DD})	Operating	3.0		26.0	V
Supply Current, (I_{DD})	B<BOP			5.0	mA
Output Saturation Voltage, (V_{sat})	$I_{OUT} = 10\text{ mA}$, B>BOP			400.0	mV
Output Leakage Current, (I_{off})	I_{OFF} B<BRP, $V_{OUT} = 12\text{V}$			10.0	uA
Power-On Time, (T_P)				50	uS
Output Switch Time, (T_{SW})				150	uS
Output Switch Frequency, (F_{SW})		3			kHz
Output Rise Time, (T_R)	$R_L=1.1\text{K}\Omega$, $C_L=20\text{pF}$			0.45	uS
Output Fall Time, (T_F)	$R_L=820\Omega$; $C_L=20\text{pF}$			0.45	uS
Electro-Static Discharge	HBM(AEQC-100)	2			KV
Operate Point, (Bop)		5(-25)		25(-5)	Gauss
Release Point, (Brp)		-25(5)		-5(25)	Gauss
Hysteresis, (BHYS)			30		Gauss

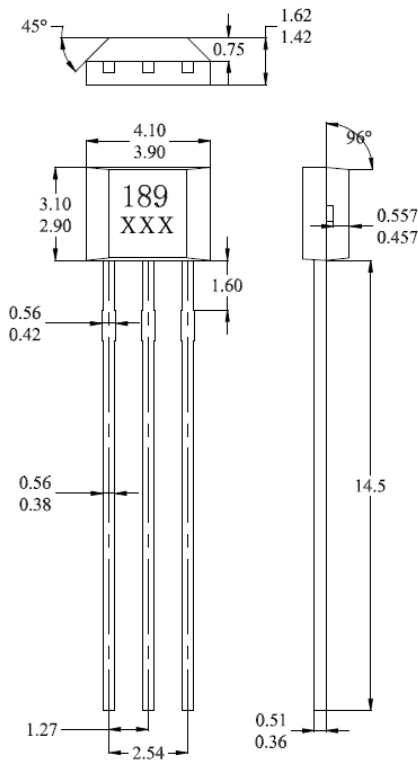
Typical application circuit



C1 : 10nF
C2 : 1nF
R1 : 1K Ω

Sensor Location, Package Dimension and Marking

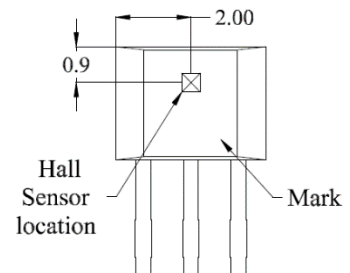
UA Package



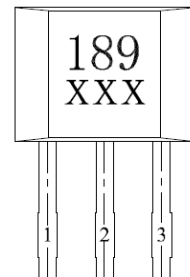
NOTES:

- 1). Controlling dimension: mm
- 2). Leads must be free of flash and plating voids
- 3). Do not bend leads within 1 mm of lead to package interface.
- 4). PINOUT:
 Pin 1 VCC
 Pin 2 GND
 Pin 3 Output

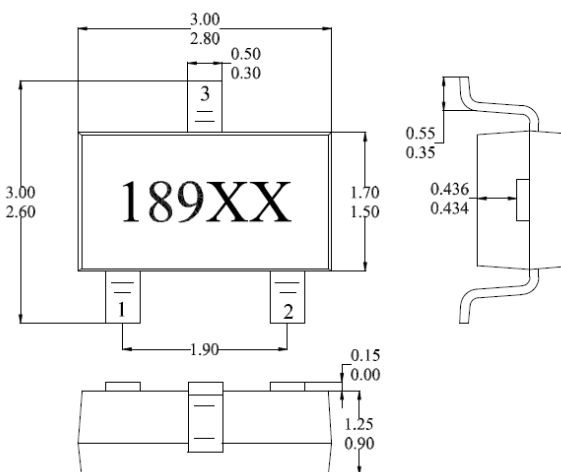
Hall Chip location



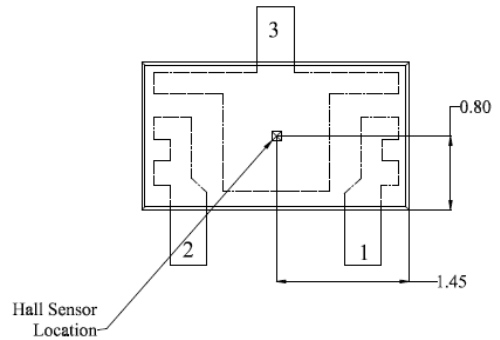
Output Pin Assignment (Top view)



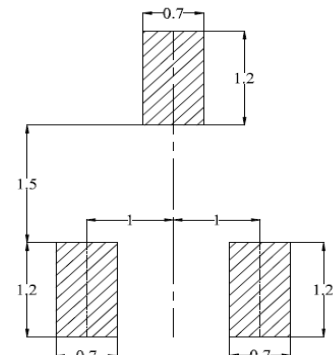
Package (SOT-23) (Top View)



Hall Plate Chip Location (Bottom view)



(For reference only) Land Pattern



NOTES:

1. PINOUT (See Top View at left :)
 Pin 1 V_{DD}
 Pin 2 Output
 Pin 3 GND
1. Controlling dimension: mm
2. Lead thickness after solder plating will be 0.254mm maximum